

KSC2383 NPN Epitaxial Silicon Transistor



Ordering Information

Part Number	Top Mark	Package	Packing Method
KSC2383OTA	C2383 O-	TO-92 3L	Ammo
KSC2383YTA	C2383 Y-	TO-92 3L	Ammo

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	160	V
V _{CEO}	Collector-Emitter Voltage	160	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current	1	Α
Ι _Β	Base Current	0.5	Α
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to +150	°C

Thermal Characteristics(1)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
P _D	Power Dissipation	900	mW
	Derate Above 25°C	7.2	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	138	°C/W

Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-Off Current	V _{CB} = 150 V, I _E = 0			1	μΑ
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 6 \text{ V}, I_{C} = 0$			1	μΑ
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, I_B = 0$	160			V
h _{FE}	DC Current Gain	$V_{CE} = 5 \text{ V}, I_{C} = 200 \text{ mA}$	60		320	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$			1.5	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA}$	0.45		0.75	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 5 \text{ V}, I_{C} = 200 \text{ mA}$	20	100		MHz
C _{ob}	Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 1 MHz			20	pF

h_{FE} Classification

Classification	R	0	Υ
h _{FE}	60 ~ 120	100 ~ 200	160 ~ 320

Typical Performance Characteristics

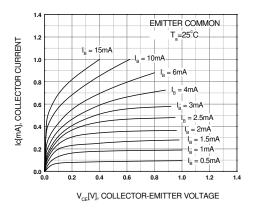


Figure 1. Static Characteristic

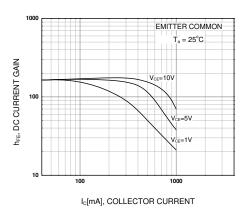


Figure 3. DC Current Gain

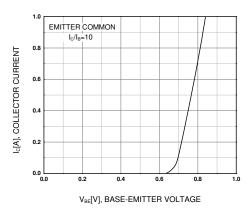


Figure 5. Base-Emitter On Voltage

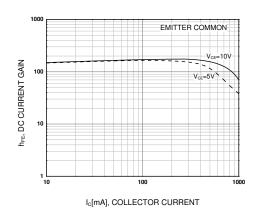


Figure 2. DC Current Gain

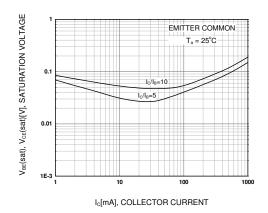
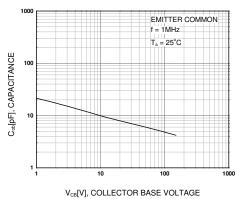


Figure 4. Collector-Emitter Saturation Voltage



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Typical Performance Characteristics (Continued)

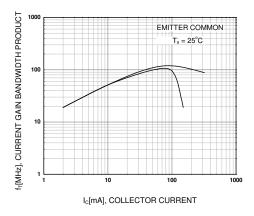


Figure 7. Current Gain Bandwidth Product

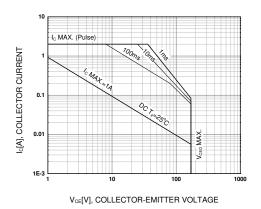


Figure 8. Safe Operating Area

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